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New Japan Radio Co.,Ltd.

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(V⁺=1.8V~15V)

DIP8, DMP8

DUAL LOW VOLTAGE POWER AMPLIFIER



■ PACKAGE OUTLINE





JRC

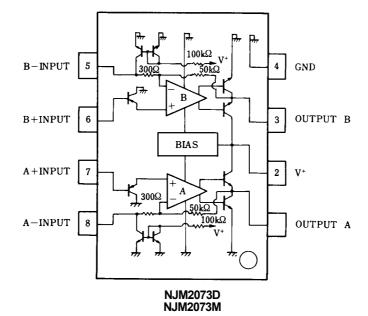
■ GENERAL DESCRIPTION

The NJM2073 is a monolithic integrated circuit in 8 lead dual-in-line package, which is designed for dual audio power amplifier in portable radio and handy cassette player.

■ FEATURES

- Operating Voltage
- Low Crossover Distortion
- Low Operating Current
- Bridge or Stereo Configuration
- No Turn-on Noise
- Package Outline
- Bipolar Technology

■ PIN CONFIGURATION



Ver.2004-03-01

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■ ABSOLUTE MAXIMUM RATINGS

			(Ta=25°C)
PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	15	V
Output Peak Current	IOP	1	A
Power Dissipation	PD	(DIP8) 700 (DMP8) 300	mW
Input Voltage Range	V _{IN}	± 0.4	V
Operating Temperature Range	T _{opr}	-40~+85	С
Storage Temperature Range	T _{stg}	-40~+125	°C

■ ELECTRICAL CHARACTERISTICS D-Type

(1) BTL Configuration (Test Circuit Fig.1) (V ⁺ =6V,Ta=25°C)						
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V ⁺		1.8	-	15	V
Operating Current	Icc	R _L =∞	-	6	9	mA
Output Offset Voltage	ΔV _O	R _L =8Ω	-	10	50	mV
(Between the Outputs)						
Input Bias Current	IB		-	100	-	nA
Output Power		THD=10%,f=1kHz				
	Po	$V^+=9V,R_L=16\Omega$ (Note)	-	2.0	-	W
	Po	$V^+=6V,R_L=8\Omega$ (Note)	0.9	1.2	-	W
	Po	V ⁺ =4.5V,R _L =8Ω	-	0.6	-	W
	Po	V^+ =4.5V,RL=4 Ω (Note)	-	0.8	-	W
	Po	$V^{+}=3V,R_{L}=4\Omega$	200	300	-	mW
	Po	$V^{+}=2V,R_{L}=4\Omega$	-	80	-	mW
		THD=1%,f=40Hz~15kHz				
	Po	V ⁺ =6V,R _L =8Ω	-	1.0	-	W
	Po	V ⁺ =4.5V,R _L =4Ω	-	0.6	-	W
Total Harmonic Distortion	THD	$P_0=0.5W,R_L=8\Omega,f=1kHz$	-	0.2	-	%
Close Loop Voltage Gain	Av	f=1kHz	41	44	47	dB
Input Impedance	Z _{IN}	f=1kHz	100	-	-	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _S =10kΩ,A Curve	-	2	-	μV
	V _{NI2}	R _S =10kΩ,B=22Hz~22kHz	-	2.5	-	μV
Ripple Rejection	RR	f=100Hz	-	40	-	dB
Cutoff Frequency	f _H	A_V =-3dB from f=1kHz,R _L =8 Ω ,P _O =1W	-	130	-	kHz

(Note) At on PC Board

NJM2073

(2) Stereo Configuration (Test Circuit Fig.2)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V		1.8	-	15	V
Output Voltage	Vo		-	2.7	-	V
Operating Current	lcc	R∟=∞	-	6	9	mA
Input Bias Current	I _B		-	100	-	nA
Output Power (Each Channel)		THD=10%,f=1kHz				
	Po	$V^{+}=6V,R_{L}=4\Omega$ (Note)	0.5	0.65	-	W
	Po	$V^{+}=4.5V,R_{L}=4\Omega$	-	0.32	-	W
	Po	V ⁺ =3V,R _L =4Ω	-	120	-	mW
	Po	V ⁺ =2V,R _L =4Ω	-	30	-	mW
		THD=1%,f=1kHz				
	Po	V ⁺ =6V,R _L =4Ω	-	500	-	mW
	Po	V ⁺ =4.5V,R _L =4Ω	-	250	-	mW
Total Harmonic Distortion	THD	P _O =0.4W,R _L =4Ω,f=1kHz	-	0.25	-	%
Voltage Gain	Av	f=1kHz	41	44	47	dB
Channel Balance	ΔA _V		-	-	±1	dB
Input Impedance	Z _{IN}	f=1kHz	100	-	-	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _s =10kΩ,A Curve	-	2.5	-	μV
-	V _{NI2}	R _S =10kΩ,B=22Hz~22kHz	-	3	-	μV
Ripple Rejection	RR	f=100Hz,C _X =100µF	24	30	-	dB
Cutoff Frequency	f _H	A_V =-3dB from f=1kHz,RL=8 Ω ,Po=250mW	-	200	-	kHz

(Note) At on PC Board

ELECTRICAL CHARACTERISTICS M-Type

(1) BTL Configuration	(Test Circuit Fig.1)
-----------------------	----------------------

(1) BTL Configuration (Test Circuit Fig.1) $(V^{+}=6V,Ta=25)$					a=25°C)	
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V ⁺		1.8	-	15	V
Operating Current	Icc	R∟=∞	-	6	9	mA
Output Offset Voltage	ΔVo	R _L =8Ω	-	10	50	mV
(Between the Outputs)						
Input Bias Current	IB		-	100	-	nA
Output Power		THD=10%,f=1kHz				
	Po	$V^+=6V,R_L=16\Omega$ (Note)	-	0.8	-	W
	Po	$V^+=4V,R_L=8\Omega$ (Note)	350	460	-	mW
	Po	$V^+=3V,R_L=4\Omega$ (Note)	200	300	-	mW
	Po	V ⁺ =2V,R _L =4Ω	-	80	-	mW
		THD=1%,f=40Hz~15kHz				
	Po	$V^{+}=4V,R_{L}=8\Omega$	-	380	-	mW
Total Harmonic Distortion	THD	V ⁺ =4V,R _L =8Ω,P _O =200mW,f=1kHz	-	0.2	-	%
Close Loop Voltage Gain	Av	f=1kHz	41	44	47	dB
Input Impedance	Z _{IN}	f=1kHz	100	-	-	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _s =10kΩ,A Curve	-	2	-	μV
	V _{NI2}	R _s =10kΩ,B=22Hz~22kHz	-	2.5	-	μV
Ripple Rejection	RR	f=100Hz	-	40	-	dB
Cutoff Frequency	f _H	A_V =-3dB from f=1kHz,RL=16 Ω ,P ₀ =0.5W	-	130	-	kHz

(Note) At on PC Board

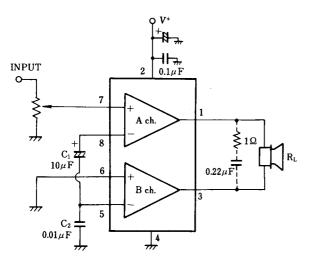
(2) Stereo Configuration (Test Circuit Fig.2)	(2) Stereo	Configuration ((Test Circuit Fig.2)
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PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V⁺		1.8	-	15	V
Output Voltage	Vo		-	2.7	-	V
Operating Current	lcc	R∟=∞	-	6	9	mA
Input Bias Current	I _B		-	100	-	nA
Output Power (Each Channel)		THD=10%,f=1kHz				
	Po	V ⁺ =6V,R _L =16Ω	-	240	-	mW
	Po	V ⁺ =5V,R _L =8Ω (Note)	-	270	-	mW
	Po	$V^{+}=4V,R_{L}=4\Omega$ (Note)	180	250	-	mW
	Po	V ⁺ =3V,R _L =4Ω	-	120	-	mW
	Po	V ⁺ =2V,R _L =4Ω	-	30	-	mW
		THD=1%,f=1kHz				
	Po	V ⁺ =4V,R _L =4Ω	-	180	-	mW
Total Harmonic Distortion	THD	$V^{+}=4V,R_{L}=4\Omega,P_{O}=150mW,f=1kHz$	-	0.25	-	%
Voltage Gain	Av	f=1kHz	41	44	47	dB
Channel Balance	ΔA _V		-	-	±1	dB
Input Impedance	Z _{IN}	f=1kHz	100	-	-	kΩ
Equivalent Input Noise Voltage	V _{NI1}	R _s =10kΩ,A Curve	-	2.5	-	μV
· · · · ·	V _{NI2}	R _s =10kΩ,B=22Hz~22kHz	-	3	-	μV
Ripple Rejection	RR	f=100Hz,C _X =100µF	24	30	-	dB
Cutoff Frequency	f _H	A_V =-3dB from f=1kHz,R _L =16\Omega,P_0=125mW	-	200	-	kHz

(Note) At on PC Board

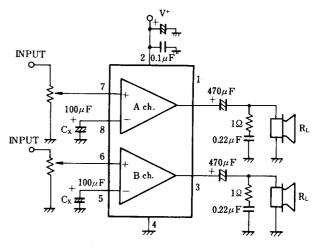
■ TYPICAL APPLICATION & TEST CIRCUIT

Fig.1 BTL Configuration



note:pin No.to D,M-Type

Fig.2 Stereo Configuration

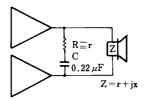


NJM2073

■ PARASTIC OSCILLATION PREVEMTING CIRCUIT

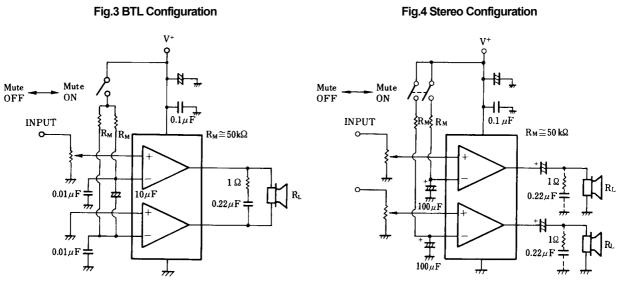
Put 1Ω +0.22µF on parallel to load, if the load is speaker. Recommend putting 0.1µF and more than 100µF capacitors with good high frequency characteristics in to near ground and supply voltage pins.

In BTL operation of less than 2V supply voltage, parastic oscillation may be occurred with $R=1\Omega$. And so recommended R to be the same value of pure resistance(r) when it is lower than 3V.



MUTING CIRCUIT

When Mute ON.OUTPUT level saturates to GND side.



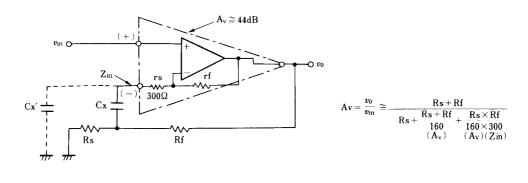
■ VOLTAGE GAIN REDUCTION APPLICATION EXAMPLE

(1) Outline of way to further Reduction

NJM2073 by taking in assamption, as one of OP-AMP (Gain 44dB, minus input impedance about 300Ω), to feedback from output to minus input helps to get reduction of stabilized Voltage Gain. Fig. 5 indicates the model example.

Here is the point to be noticed that, in order to get the appropriate output Bias Voltage, it is important to keep the minus input floating as DC condition, (inserting C_x), and also that when extended too much reduction of Gain might cause Oscillation due to high band phase margin. The reduction of voltage gain is limited at around 26dB (20 times), and when oscillation, it in necessary to attach the oscillation stopper. Please examine the C_x value accordingly to the application requirement.

Fig.5 Model of Voltage Gain Reduction



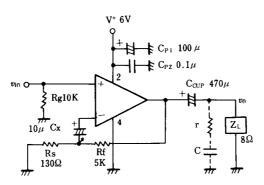
(2) The Application Example of Voltage Gain Reduction. (STEREO)

Fig.6 indicates the application example and Table1 indicates the recommendable value of parts to be attached externally.

EXTERNAL PARTS	APPLICATION PURPOSE	RECOMMENDED VALUE	REMARKS
R _g	Plus input to be grounded by fixed DC	Under about $100k\Omega$	Catch the noise when much higher.
Rs	AV shall be decided with R _f	-	
R _f	AV shall be decided with $R_{\!s}$	About 5kΩ	The co-temperature of AV becomes higher in case when R_s is higher resistance. The current from output pin to GND becomes higher, in case when R_s is lower resistance. (The current sinks in vain.)
C _X	Minus input to be grounded by fixed DC	-	Low-band Cut off frequency (fL) is to be decided. The rise time becomes longer in case that C_X is big.
C _{CUP}	Output DC Decoupling	When R _L =8Ω,More than 220μF	fL shall be decided by C_{CUP} and Z_L .
C _{P1}	Stabilization of V ⁺	More than about C _{CUP}	Inserting near around V^{\dagger} pin and GND pin.
C _{P2}	Prevention of Oscillation	More than 0.1µF	
r	Prevention of Oscillation	About RL	Inserting near around V^{\dagger} pin and GND pin.
С	Prevention of Oscillation	0.22µF	To be examined by about the resistor volume of the speaker load.

Table1, Applicating purpose and Recommended Value of Externally parts to be attached.

Fig.6 STEREO Application Example.



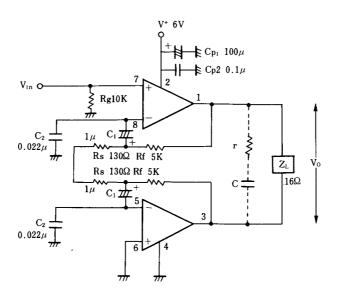
• Application for Voltage Gain Reduction (BTL)

Fig.7 indicates the application example, Table2 shows recommended value of externally attaching parts.

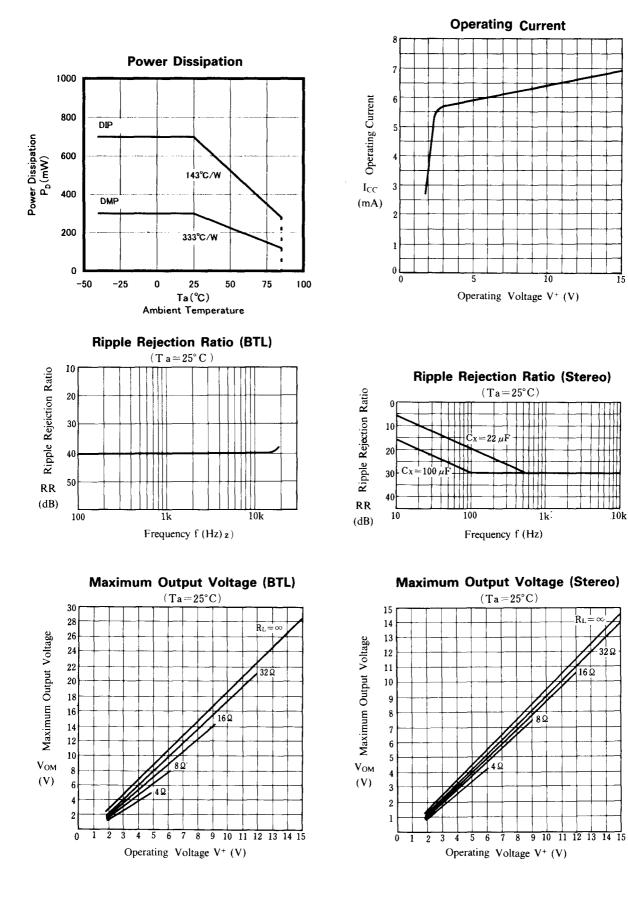
EXTERNAL PARTS	APPLICATION PURPOSE	RECOMMENDED VALUE	REMARKS
R _g	DC condition ground of plus input	Below about 10kΩ	Making noise when higher.
Rs	AV shall be decided with R _f	-	
R _f	AV shall be decided with $R_{\!s}$	About 5kΩ	Temperature feature to be increased accordingly as in higher AV value. When lower,to be trended of Oscillation.
C ₁	Releasing minus input in to DC condition	-	Setting up low band Cut-off frequency (fL). More higher,the rise time become longer.
C ₂	Preventing Oscillation	About 0.02µF	The more higher in value, the high band THD, due to phase slipping to be deteriorated. When lower, to be trended of oscillation.
C _{P1}	Stability of V ⁺ Preventing Oscillation	More than about 100µF	Inserting near around at V^{\dagger} and the GND pin.
C _{P2}	Preventing Oscillation	More than 0.1µF	Inserting near around at V^{\dagger} and the GND pin.
r	Preventing Oscillation	About RL	To be examined at around pure resister Value of speaker load.
С	Preventing Oscillation	0.22µF	

Table2 Applicating purpose and Recommended Value of External Part

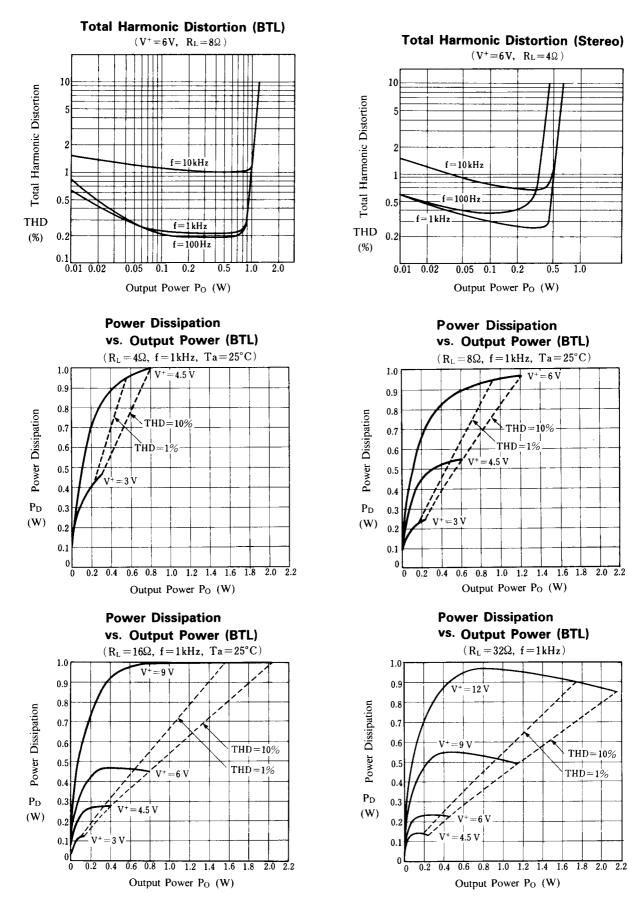
Fig.7 BTL Application



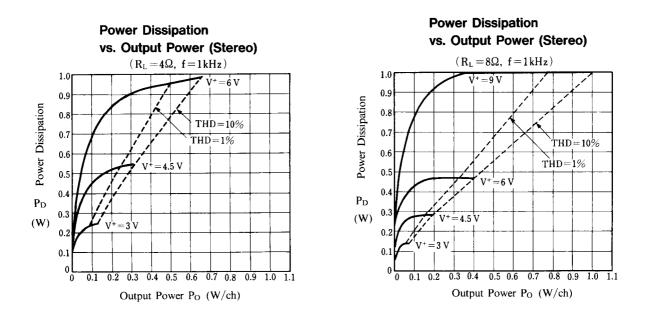
TYPICAL CHARACTERISTICS

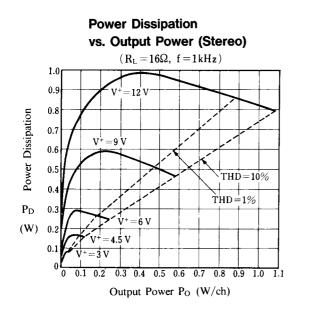


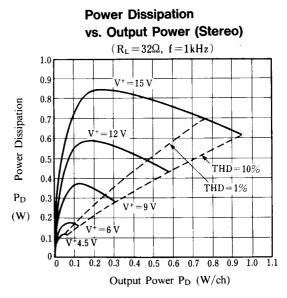
TYPICAL CHARACTERISTICS



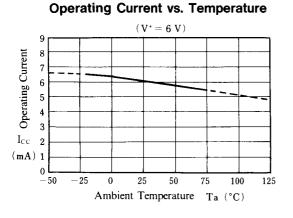
TYPICAL CHARACTERISTICS

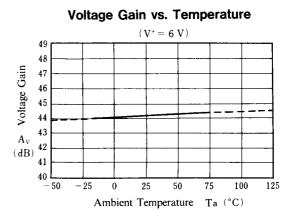






■ TYPICAL CHARACTERISTICS





Channel Separation vs. Frequency $(V^{*} = 6 V, R_{s} = 50 k\Omega, Ta = 25^{\circ}C)$ 60 Channel Separation 50 40 30 20 C_{s} 10 (dB)0 10 100 $1 \, k$ 10k 100k Frequency f(Hz)

[CAUTION]

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